

# TS824-2.5

# HIGH THERMAL STABILITY MICROPOWER SHUNT VOLTAGE REFERENCE

- LOW Tc: 50 ppm/°C MAXIMUM
- 2.5V OUTPUT VOLTAGE
- LOW OPERATING CURRENT: 60μA max @ 25°C

WWW.DZSG

- HIGH PRECISION AT 25°C: ±0.5% AND ±1%
- STABLE WHEN USED WITH CAPACITIVE LOADS
- INDUSTRIAL TEMPERATURE RANGE: -40 to +85°C

#### **DESCRIPTION**

The TS824-2.5 is a low power shunt voltage reference featuring a very low temperature coefficient of 50ppm/°C as a maximum value. Providing a 2.5V output voltage, the TS824-2.5 operates over the industrial temperature range (-40 to +85°C). Ideal for battery-powered equipments where power conservation is critical, the TS824 is housed in a tiny SOT23-3 package allowing space saving.

The TS824 is typically stable with any capacitive loads within the entire temperature range. The product is thus easy to use and the design simplified.

#### **APPLICATION**

- Instrumentation.
- Data acquisition systems,
- Portable, Battery powered equipments
- Power management

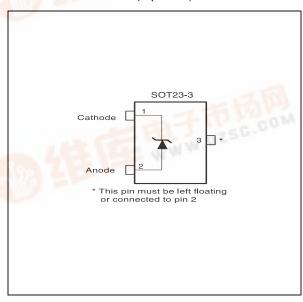
#### **ORDER CODE**

Voltage	Precision	SOT23-3	SOT23 Marking		
2.5V	±1%	TS824ILT-2.5	L252		
	±0.5%	TS824AILT-2.5	L253		
Single temperature range: -40 to +85°C					

LT = Tiny Package (SOT23-3) - only available in Tape & Reel (LT)



#### PIN CONNECTIONS (top view)





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
I <sub>K</sub>	Reverse Breakdown Current	20	mA
I <sub>F</sub>	Forward Current	10	mA
P <sub>D</sub>	Power Dissipation (note1) SOT23-3	360	mW
T <sub>Std</sub>	Storage Temperature	-65 to +150	°C
ESD	Human Body Model (HBM) (note2)	2	kV
	Machine Model (MM) (note 2)	200	V
T <sub>Lead</sub>	Lead Temperature (soldering, 10 seconds)	260	°C

**Note 1:** The maximum power dissipation must be derated at high temperature. It can be calculated using  $T_{JMAX}$  (maximum junction temperature),  $R_{THJA}$  (Thermal resistance junction to ambient) and  $T_A$  (Ambient temperature). The maximum power dissipation formula at any temperature is  $P_{DMAX} = (T_{JMAX} - T_A) / R_{THJA}$ .  $R_{THJA}$  is 340°C/W for the SOT23-3 package.

Note 2: The Human Body Model (HBM) is defined as a 100pF capacitor discharge through a 1.5kΩ resistor into each pin. The Machine Mode (MM) is defined as a 200pF capacitor discharge directly into each pins.

### **OPERATING CONDITIONS**

Symbol	Parameter	Value	Unit
I <sub>min</sub>	Minimum Operating Current	60	μΑ
I <sub>max</sub>	Maximum Operating Current	15	mA
T <sub>oper</sub>	Operating Free Air Temperature Range	-40 to +85	°C

## **ELECTRICAL CHARACTERISTICS (note 3)**

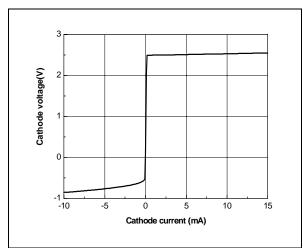
 $T_{amb} = 25$ °C (unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit	
	Poverse Prockdown Voltage	I <sub>K</sub> = 100μA, ±0.5%	2.4875	2.500	2.5125	V	
	Reverse Breakdown Voltage	I <sub>K</sub> = 100μA, ±1%	2.475	2.500	2.525		
V <sub>K</sub>	Reverse Breakdown Voltage Tolerance	$I_K = 100\mu A, \pm 0.5\%$ -40°C < $T_{amb}$ < +85°C	-12.5 -20		+12.5 +20	mV	
		$I_K = 100\mu A, \pm 1\%$ -40°C < $T_{amb}$ < +85°C	-25 -33		+25 +33		
I <sub>KMIN</sub> Minimum Operating (	Minimum Operating Current	T <sub>amb</sub> = 25°C		50	60	^	
'KMIN	Minimum Operating Current	-40°C < T <sub>amb</sub> < +85°C			65	μΑ	
$\Delta V_{K}/\!\Delta T$	Average Temperature Coefficient (note 5)	I <sub>K</sub> = 100μA			50	ppm/°C	
$\Delta V_{K}/\Delta I_{K}$	Reverse Breakdown Voltage Change	$I_{\text{KMIN}} < I_{\text{K}} < 1 \text{mA}$ -40°C < $T_{\text{amb}}$ < +85°C		0.4	1 1.2	m\/	
with Operating Current Range		1mA < I <sub>K</sub> < 15mA -40°C < T <sub>amb</sub> < +85°C		4.5	8 10	mV	
R <sub>KA</sub> S	Static Impedance	$\Delta I_K = I_{KMIN}$ to 1mA -40°C < $T_{amb}$ < +85°C		0.4	1 1.2		
		$\Delta I_{K} = 1 \text{mA to } 15 \text{mA}$ -40°C < T <sub>amb</sub> < +85°C		0.3	0.6 0.7	Ω	
$K_{VH}$	Long Term Stability	$I_K = 100 \mu A$ , $t = 1000 hrs$		120		ppm	
E <sub>N</sub>	Wide Band Noise	$I_K = 100\mu A$ 100Hz < f < 10kHz		350		nV/√Hz	

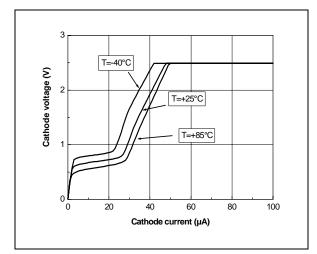
Note 3: Limits are 100% production tested at 25°C. Limits over temperature are guaranteed through correlation and by design.

Note 4: The total tolerance within the industrial range, where the maximum  $\Delta T$  versus 25°C is 65°C, is explained hereafter:  $\pm$  1 % + ( $\pm$  50 ppm/°C x 65°C) =  $\pm$  1.325 %

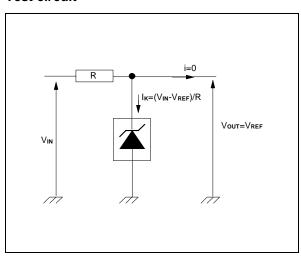
## Reference voltage versus cathode current



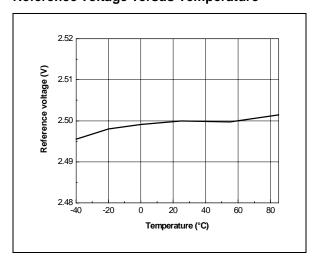
## Reference voltage versus cathode current



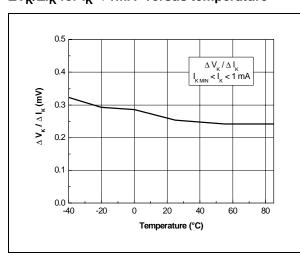
### **Test circuit**



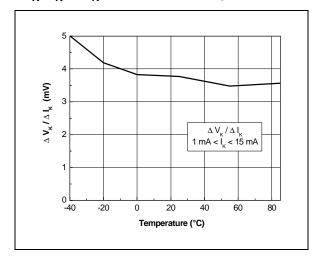
Reference voltage versus Temperature



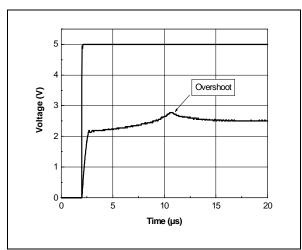
## $\Delta V_{\mbox{\scriptsize K}}/\Delta I_{\mbox{\scriptsize K}}$ for $I_{\mbox{\scriptsize K}}<1m\mbox{\scriptsize A}$ versus temperature



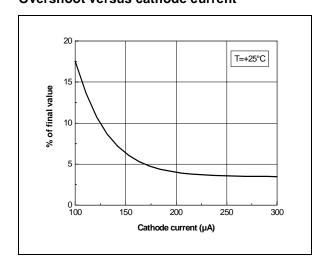
 $\Delta V_{\mbox{\scriptsize K}}/\Delta I_{\mbox{\scriptsize K}}$  for  $I_{\mbox{\scriptsize K}}$  > 1mA  $\,$  versus temperature



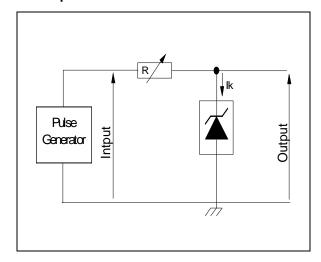
## Start-up response with low cathode current



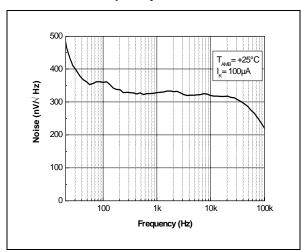
# Overshoot versus cathode current



## Start-up schematic with low cathode current

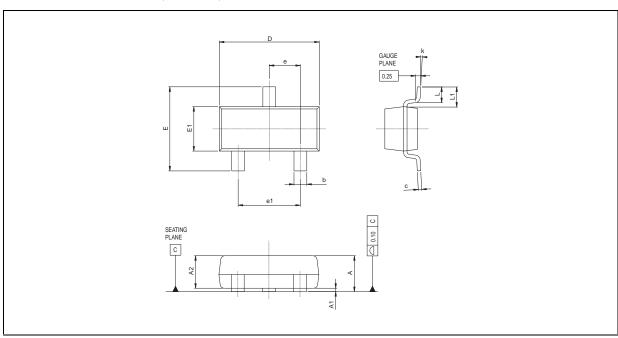


## Noise versus frequency



## **PACKAGE MECHANICAL DATA**

3 PINS - TINY PACKAGE (SOT23-3)



Dimensions	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	0.890		1.120	0.035		0.044	
A1	0.010		0.100	0.0004		0.004	
A2	0.880	0.950	1.020		0.037	0.040	
b	0.300		0.500	0.012		0.020	
С	0.080		0.200	0.003		0.008	
D	2.800	2.900	3.040	0.110	0.114	0.120	
E	2.100		2.640	0.083		0.104	
E1	1.200	1.300	1.400	0.047	0.051	0.055	
е		0.950			0.037		
e1		1.900			0.075		
L	0.400	0.500	0.600	0.016	0.020	0.024	
L1		0.540			0.021		
k	0°		8°				

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